

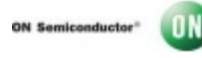

	Hersteller-Teilenummer: NTD4963NT4G
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 30V 8.1A DPAK
	Datenblätter:  NTD4963NT4G.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 45597 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.	

Spezifikationen

Teilenummer	NTD4963NT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 8.1A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	45597 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.1W (Ta), 35.7W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	8.1A (Ta), 44A (Tc)
Rds On (Max) @ Id, Vgs	9.6 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16.2nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1035pF @ 12V
Verpackung	Tape & Reel (TR)



















































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 <p>NTD4963N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.1A IPAK</p>	 <p>NTD4963N ON NTD4963N ON</p>	 <p>NTD4963N-1 AMI Semiconductor / ON Semiconductor NTD4963N-1 ON</p>	 <p>NTD4965N ON NTD4965N ON</p>
 <p>NTD4963N-1G O NTD4963N-1G O</p>	 <p>NTD4969N ON NTD4969N ON</p>	 <p>NTD4965NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 68A DPAK</p>	 <p>NTD4960NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11.1A DPAK</p>

heiße Teile

Mehr

 NTD4906N	 NTD4906N-1G	 NTD4906N-35G	 NTD4906NAS1	 NTD4906NAT4G
 NTD4906NAT4H	 NTD4906NT4G	 NTD4906NT4H	 NTD4909N	 NTD4909N-35G
 NTD4909NAT4H	 NTD4909NT4G	 NTD4910N	 NTD4910N-1G	 NTD4910NT4G
 NTD4913N	 NTD4959NHT4G	 NTD4959NT4G	 NTD4960N	 NTD4960N-1G
 NTD4960NT4G	 NTD4963N	 NTD4963N-1	 NTD4963N-1G	 NTD4963N-35G
 NTD4965N	 NTD4965N-35G	 NTD4965NT4G	 NTD4969N	 NTD4969N-1
 NTD4969N-1G	 NTD4969NT4G	 NTD4970N	 NTD4970N-1	 NTD4970N-1G
 NTD4970N-35G	 NTD4970NT4G	 NTD50N03R-001	 NTD50N03R-035	 NTD50N03R-1G
 NTD50N03R-35G	 NTD50N03RG	 NTD50N03RT4	 NTD50N03RT4G	 NTD50N03T4G
 NTD50N06	 NTD5406N	 NTD5406NG	 NTD5406NT4G	 NTD5406T4G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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